



CMOS INTEGRATED CIRCUIT

μ PD5713TK

WIDE BAND SPDT SWITCH

DESCRIPTION

The μ PD5713TK is a CMOS MMIC for wide band SPDT (Single Pole Double Throw) switch which were developed for mobile communications, wireless communications and another general-purpose RF switching application.

This device can operate frequency from 0.05 to 2.5 GHz, having the low insertion loss and high isolation.

This device is housed in a 6-pin lead-less minimold (1511) package. And this package is able to high-density surface mounting.

FEATURES

- Supply voltage : $V_{DD} = 1.8$ to 3.6 V (2.8 V TYP.)
- Switch control voltage : $V_{cont(H)} = 1.8$ to 3.6 V (2.8 V TYP.)
: $V_{cont(L)} = -0.2$ to $+0.4$ V (0 V TYP.)
- Low insertion loss : $L_{ins1} = 0.6$ dB TYP. @ $f = 0.05$ to 1.0 GHz, $V_{DD} = 2.8$ V, $V_{cont(H)} = 2.8$ V, $V_{cont(L)} = 0$ V
: $L_{ins2} = 0.8$ dB TYP. @ $f = 1.0$ to 2.0 GHz, $V_{DD} = 2.8$ V, $V_{cont(H)} = 2.8$ V, $V_{cont(L)} = 0$ V
: $L_{ins3} = 0.95$ dB TYP. @ $f = 2.0$ to 2.5 GHz, $V_{DD} = 2.8$ V, $V_{cont(H)} = 2.8$ V, $V_{cont(L)} = 0$ V
- High isolation : $ISL1 = 32.5$ dB TYP. @ $f = 0.05$ to 1.0 GHz, $V_{DD} = 2.8$ V, $V_{cont(H)} = 2.8$ V, $V_{cont(L)} = 0$ V
: $ISL2 = 25$ dB TYP. @ $f = 1.0$ to 2.0 GHz, $V_{DD} = 2.8$ V, $V_{cont(H)} = 2.8$ V, $V_{cont(L)} = 0$ V
: $ISL3 = 22.5$ dB TYP. @ $f = 2.0$ to 2.5 GHz, $V_{DD} = 2.8$ V, $V_{cont(H)} = 2.8$ V, $V_{cont(L)} = 0$ V
- Handling power : $P_{in(1dB)} = +21.0$ dBm TYP. @ $f = 1.0$ GHz, $V_{DD} = 2.8$ V, $V_{cont(H)} = 2.8$ V, $V_{cont(L)} = 0$ V
: $P_{in(0.1dB)} = +17.0$ dBm TYP. @ $f = 1.0$ GHz, $V_{DD} = 2.8$ V, $V_{cont(H)} = 2.8$ V, $V_{cont(L)} = 0$ V
- High-density surface mounting : 6-pin lead-less minimold package ($1.5 \times 1.1 \times 0.55$ mm)

APPLICATIONS

- Mobile communications
- Wireless communications
- Another general-purpose RF switching applications

ORDERING INFORMATION

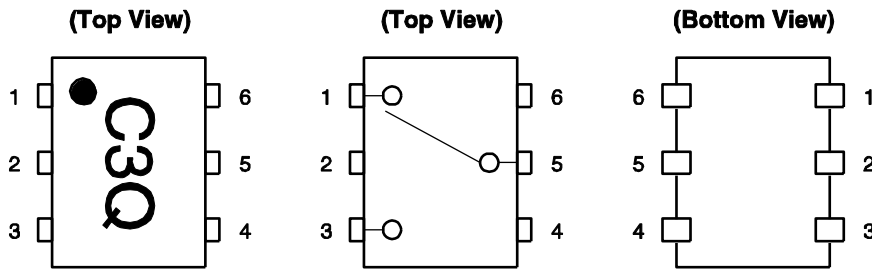
Part Number	Order Number	Package	Marking	Supplying Form
μ PD5713TK-E2	μ PD5713TK-E2-A	6-pin lead-less minimold (1511) (Pb-Free)	C3Q	<ul style="list-style-type: none">• Embossed tape 8 mm wide• Pin 1, 6 face the perforation side of the tape• Qty 5 kpcs/reel

Remark To order evaluation samples, contact your nearby sales office.
Part number for sample order: μ PD5713TK-A

Caution: Observe precautions when handling because these devices are sensitive to electrostatic discharge

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

PIN CONNECTIONS AND INTERNAL BLOCK DIAGRAM



Pin No.	Pin Name
1	OUTPUT1
2	GND
3	OUTPUT2
4	V _{cont}
5	INPUT
6	V _{DD}

TRUTH TABLE

V _{cont}	INPUT-OUTPUT1	INPUT-OUTPUT2
Low	OFF	ON
High	ON	OFF

ABSOLUTE MAXIMUM RATINGS (T_A = +25°C, unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Supply Voltage	V _{DD}	-0.5 to +4.6	V
Switch Control Voltage	V _{cont}	-0.5 to +4.6	V
Voltage Difference	V _{cont (H)} - V _{DD}	+0.5	V
Input Power	P _{in}	+23	dBm
Operating Ambient Temperature	T _A	-45 to +85	°C
Storage Temperature	T _{stg}	-55 to +150	°C

RECOMMENDED OPERATING RANGE (T_A = +25°C, unless otherwise specified)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Supply Voltage	V _{DD}	+1.8	+2.8	+3.6	V
Switch Control Voltage (H)	V _{cont (H)}	+1.8	+2.8	+3.6	V
Switch Control Voltage (L)	V _{cont (L)}	-0.2	0	+0.4	V

Remark V_{DD} - 0.4 V ≤ V_{cont (H)} ≤ V_{DD} + 0.2 V

ELECTRICAL CHARACTERISTICS

($T_A = +25^\circ\text{C}$, $V_{DD} = 2.8\text{ V}$, $V_{\text{cont (H)}} = 2.8\text{ V}$, $V_{\text{cont (L)}} = 0\text{ V}$, DC cut capacitors = 1 000 pF, unless otherwise specified)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Insertion Loss 1	L_{ins1}	$f = 0.05\text{ to }1.0\text{ GHz}$	–	0.6	0.8	dB
Insertion Loss 2	L_{ins2}	$f = 1.0\text{ to }2.0\text{ GHz}$	–	0.8	1.0	dB
Insertion Loss 3	L_{ins3}	$f = 2.0\text{ to }2.5\text{ GHz}$	–	0.95	1.2	dB
Isolation 1	$ISL1$	$f = 0.05\text{ to }1.0\text{ GHz}$	30	32.5	–	dB
Isolation 2	$ISL2$	$f = 1.0\text{ to }2.0\text{ GHz}$	22	25	–	dB
Isolation 3	$ISL3$	$f = 2.0\text{ to }2.5\text{ GHz}$	20	22.5	–	dB
Input Return Loss	RL_{in}	$f = 0.05\text{ to }2.5\text{ GHz}$	13	17	–	dB
Output Return Loss	RL_{out}	$f = 0.05\text{ to }2.5\text{ GHz}$	13	17	–	dB
0.1 dB Loss Compression Input Power ^{Note 1}	$P_{\text{in (0.1 dB)}}$	$f = 1.0\text{ GHz}$	+13.0	+17.0	–	dBm
1 dB Loss Compression Input Power ^{Note 2}	$P_{\text{in (1 dB)}}$	$f = 1.0\text{ GHz}$	–	+21.0	–	dBm
Supply Current	I_{DD}	$V_{DD} = V_{\text{cont}} = 2.8\text{ V}$, RF off	–	0.01	1.0	μA
Switch Control Current	I_{cont}	$V_{DD} = V_{\text{cont}} = 2.8\text{ V}$, RF off	–	0.01	1.0	μA
Switch Control Speed	t_{sw}	$f = 1.0\text{ GHz}$	–	30	100	ns

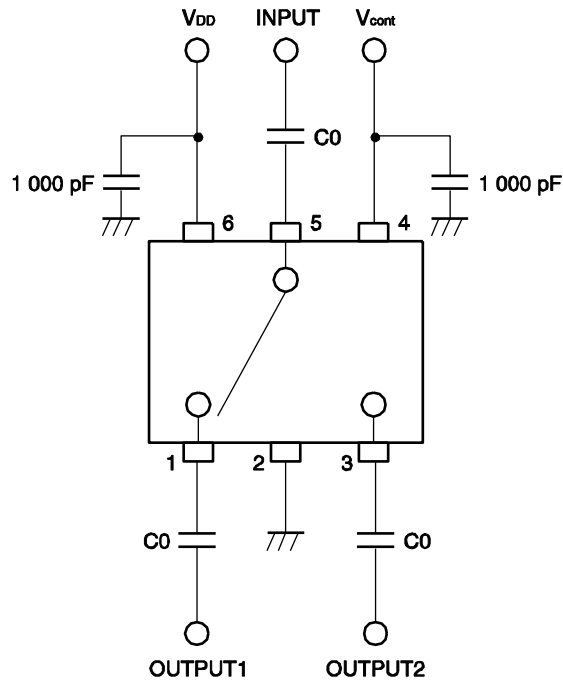
Notes 1. $P_{\text{in (0.1 dB)}}$ is measured the input power level when the insertion loss increases more 0.1 dB than that of linear range.

2. $P_{\text{in (1 dB)}}$ is measured the input power level when the insertion loss increases more 1 dB than that of linear range.

Caution This device is used it is necessary to use DC cut capacitors.

The value of DC cut capacitors should be chosen to accommodate the frequency of operation, bandwidth, switching speed and the condition with actual board of your system.

EVALUATION CIRCUIT

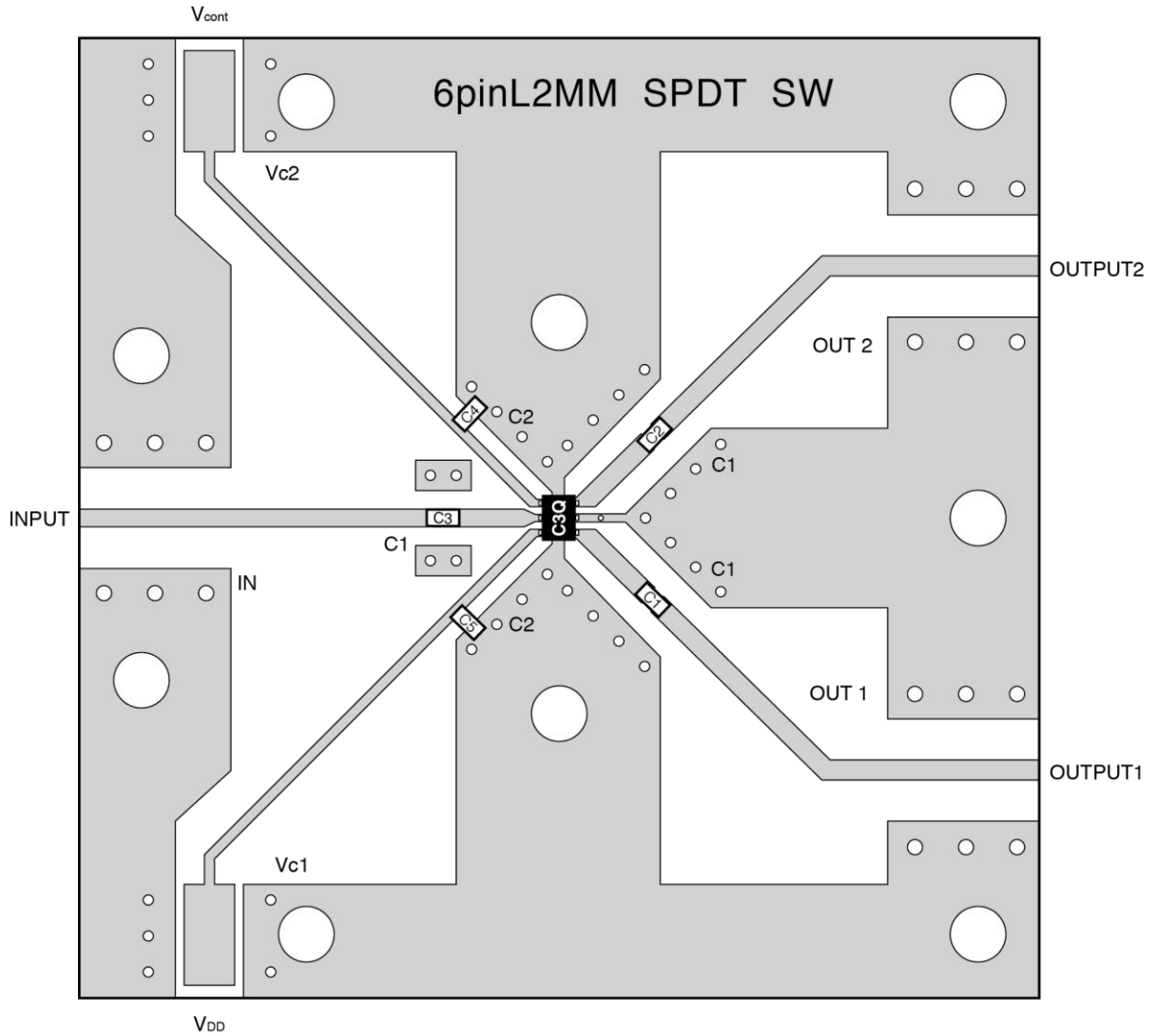


Remark C0 = 1 000 pF

Caution This IC has pull down resistance between RF line and GND, witch fixes electric potential of RF line to 0 V, then the IC cannot be used for DC switching.

The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.

ILLUSTRATION OF THE TEST CIRCUIT ASSEMBLED ON EVALUATION BOARD



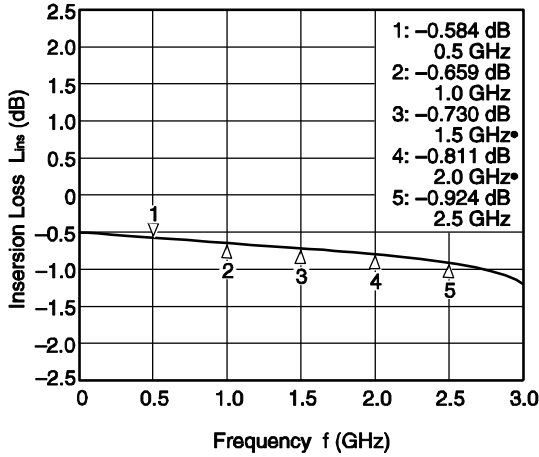
USING THE EVALUATION BOARD

Symbol	Values
C1, C2, C3	1 000 pF
C4, C5	1 000 pF

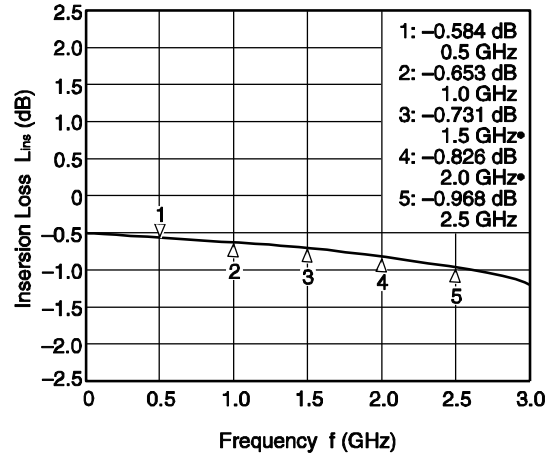
TYPICAL CHARACTERISTICS

($T_A = +25^\circ\text{C}$, $V_{DD} = 2.8\text{ V}$, $V_{\text{cont (H)}} = 2.8\text{ V}$, $V_{\text{cont (L)}} = 0\text{ V}$, $P_{\text{in}} = 0\text{ dBm}$, DC cut capacitors = 1 000 pF, unless otherwise specified)

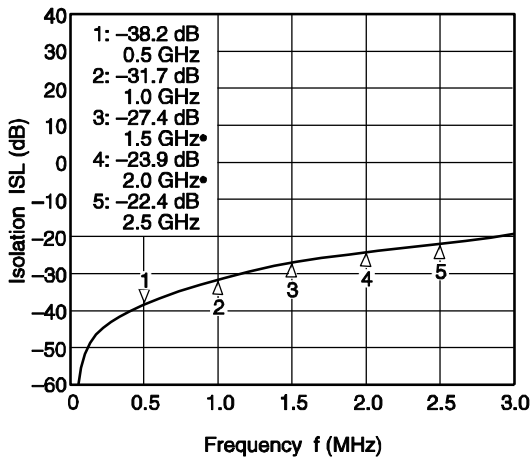
**INPUT-OUTPUT1 •
INSERTION LOSS vs. FREQUENCY**



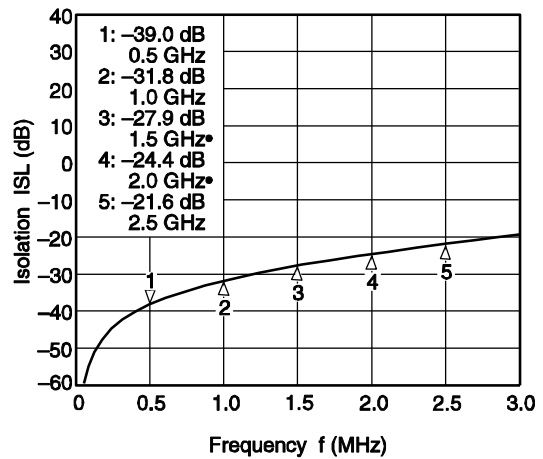
**INPUT-OUTPUT2 •
INSERTION LOSS vs. FREQUENCY**



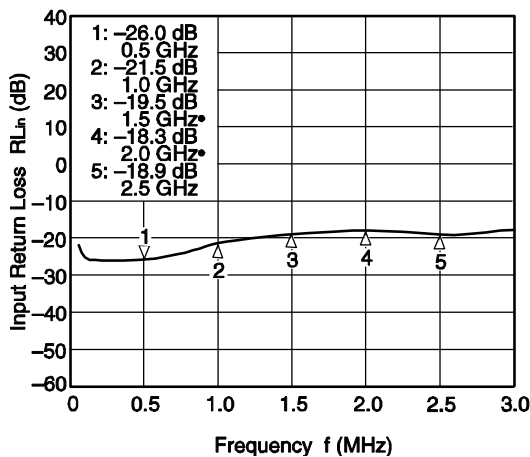
**INPUT-OUTPUT1 •
ISOLATION vs. FREQUENCY**



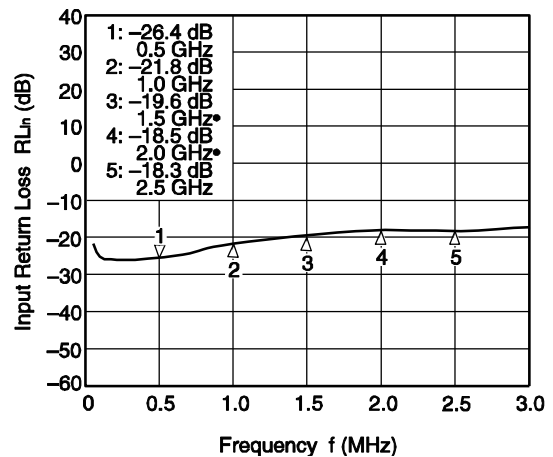
**INPUT-OUTPUT2 •
ISOLATION vs. FREQUENCY**



**INPUT-OUTPUT1 •
INPUT RETURN LOSS vs. FREQUENCY**

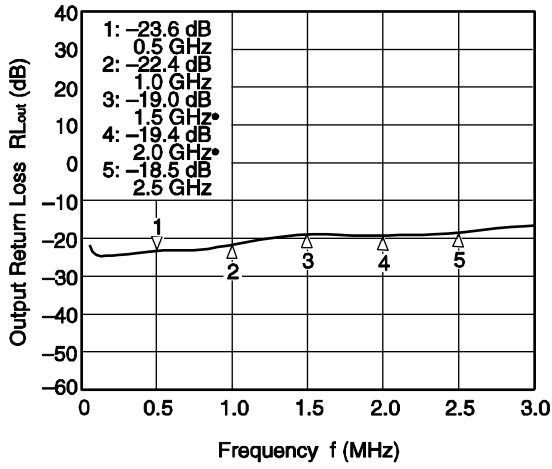


**INPUT-OUTPUT2 •
INPUT RETURN LOSS vs. FREQUENCY**

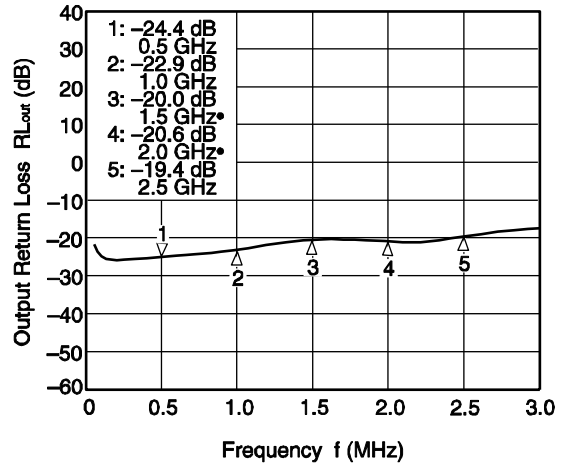


Remark The graphs indicate nominal characteristics.

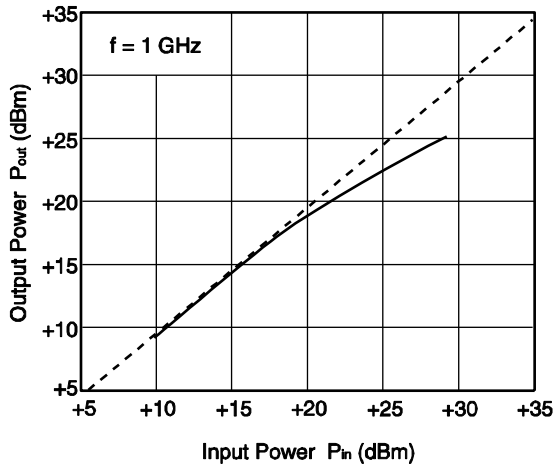
INPUT-OUTPUT1 •
OUTPUT RETURN LOSS vs. FREQUENCY



INPUT-OUTPUT2 •
OUTPUT RETURN LOSS vs. FREQUENCY



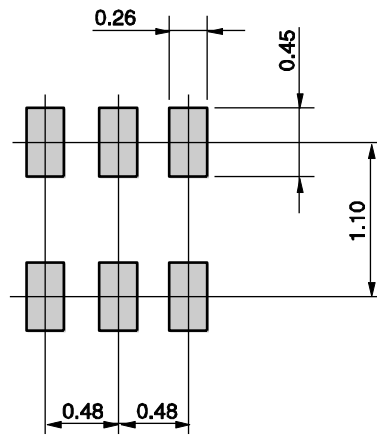
OUTPUT POWER vs. INPUT POWER



Remark The graphs indicate nominal characteristics.

MOUNTING PAD DIMENSIONS

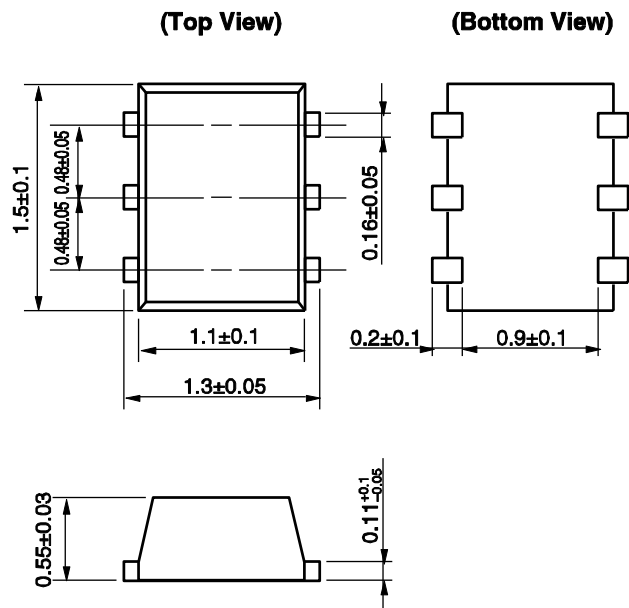
6-PIN LEAD-LESS MINIMOLD (1511) (UNIT: mm)



Remark The mounting pad layouts in this document are for reference only.

PACKAGE DIMENSIONS

6-PIN LEAD-LESS MINIMOLD (1511) (UNIT: mm)



RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions	Condition Symbol
Infrared Reflow	Peak temperature (package surface temperature) : 260°C or below Time at peak temperature : 10 seconds or less Time at temperature of 220°C or higher : 60 seconds or less Preheating time at 120 to 180°C : 120±30 seconds Maximum number of reflow processes : 3 times Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	IR260
Wave Soldering	Peak temperature (molten solder temperature) : 260°C or below Time at peak temperature : 10 seconds or less Preheating temperature (package surface temperature) : 120°C or below Maximum number of flow processes : 1 time Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	WS260
Partial Heating	Peak temperature (terminal temperature) : 350°C or below Soldering time (per side of device) : 3 seconds or less Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	HS350

Caution Do not use different soldering methods together (except for partial heating).

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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